

SMBG Plastic-Encapsulate Diodes

High Efficient Rectifier

Features

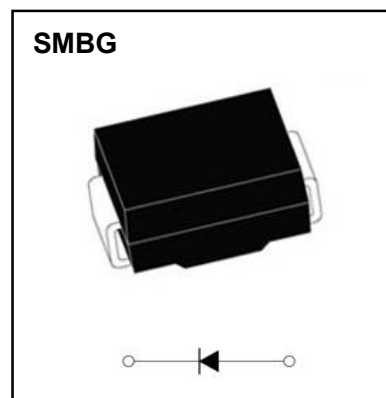
- I_o 3A
- V_{RRM} 50V-1000V
- High surge current capability
- Glass passivated chip
- Polarity: Color band denotes cathode

Applications

- Rectifier

Marking

- US3X
- X : From A To M



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	US3							
				AB	BB	DB	FB	GB	JB	KB	MB
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	300	400	600	800	1000
Maximum RMS Voltage	V_{RMS}	V		35	70	140	210	280	420	560	700
Average Forward Current	$I_{F(AV)}$	A	60HZ Half-sine wave, Resistance load, $T_L = 110^\circ\text{C}$	3							
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz Half-sine wave, 1 cycle, $T_a = 25^\circ\text{C}$	100							
Junction Temperature	T_J	$^\circ\text{C}$		-55~+150							
Storage Temperature	T_{STG}	$^\circ\text{C}$		-55 ~ +150							

Electrical Characteristics ($T_a = 25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	US3							
				AB	BB	DB	FB	GB	JB	KB	MB
Peak Forward Voltage	V_F	V	$I_F = 3.0\text{A}$	1.0			1.3		1.7		
Maximum reverse recovery time	t_{rr}	ns	$I_F = 0.5\text{A}, I_R = 1.0\text{A}, I_{rr} = 0.25\text{A}$	50						75	
Peak Reverse Current	I_{RRM1}	μA	$V_{RM} = V_{RRM}$	$T_a = 25^\circ\text{C}$				10			
	I_{RRM2}			$T_a = 100^\circ\text{C}$				200			
Thermal Resistance(Typical)	$R_{\theta J-A}$	$^\circ\text{C/W}$	Between junction and ambient		47 ¹⁾						
	$R_{\theta J-L}$		Between junction and terminal		13 ¹⁾						

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.27" x 0.27" (7.0 mm x 7.0 mm)^{er} copper pad areas

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

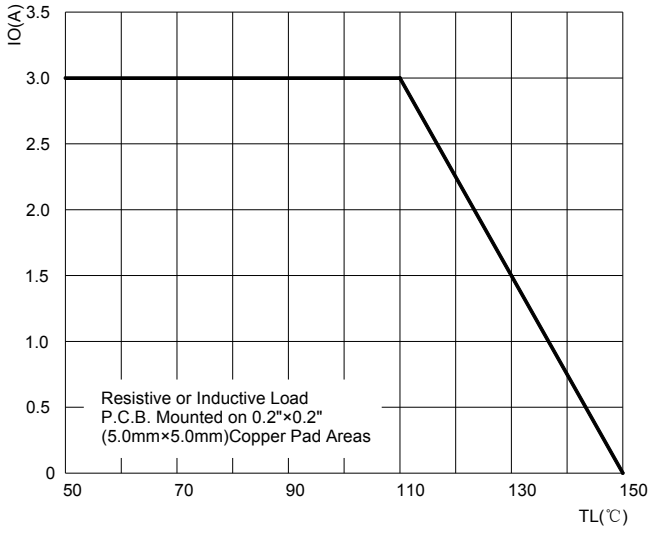


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

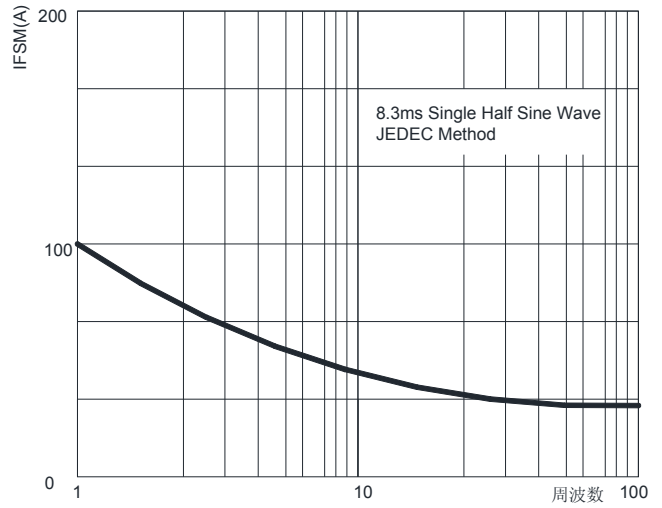


FIG.3: TYPICAL FORWARD CHARACTERISTICS

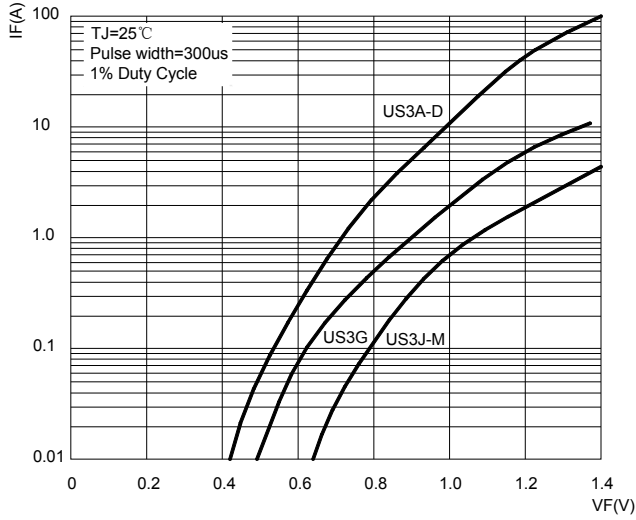


FIG.4: TYPICAL REVERSE CHARACTERISTICS

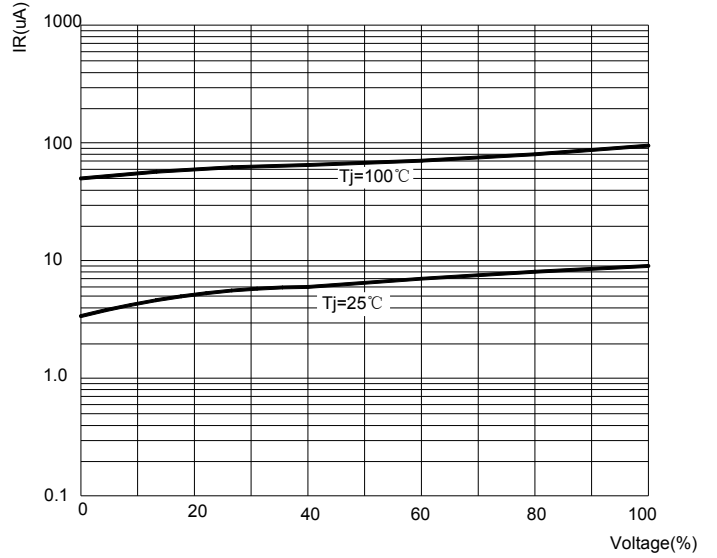
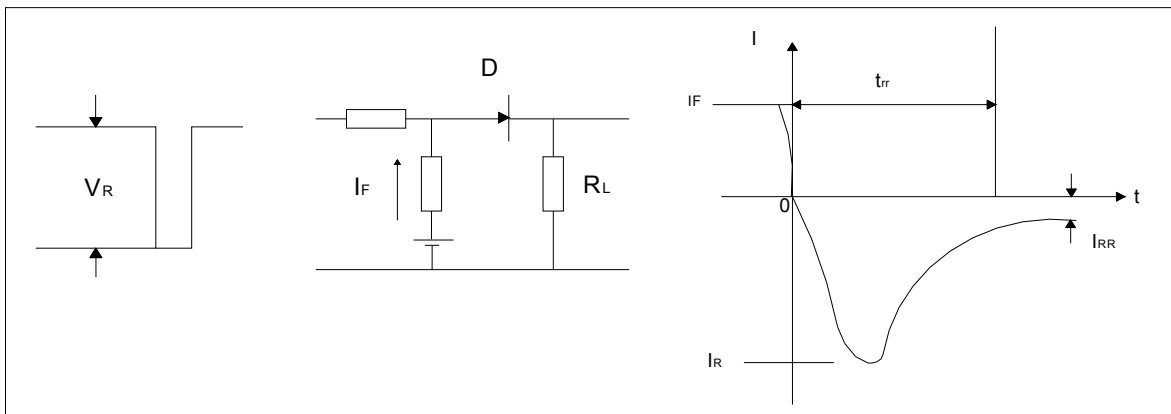
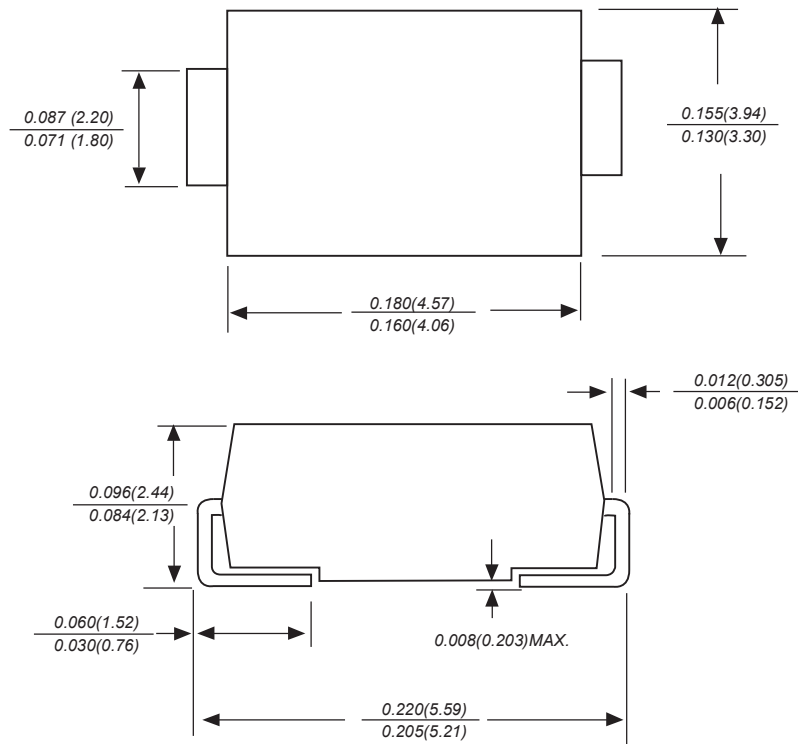


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

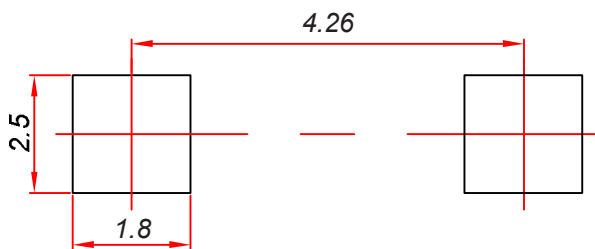


SMBG Package Outline Dimensions



Dimensions in inches and (millimeters)

SMBG Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSMD reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSMD does not assume any liability arising out of the application or use of any product described herein.

Reel Taping Specifications For Surface Mount Devices–SMBG

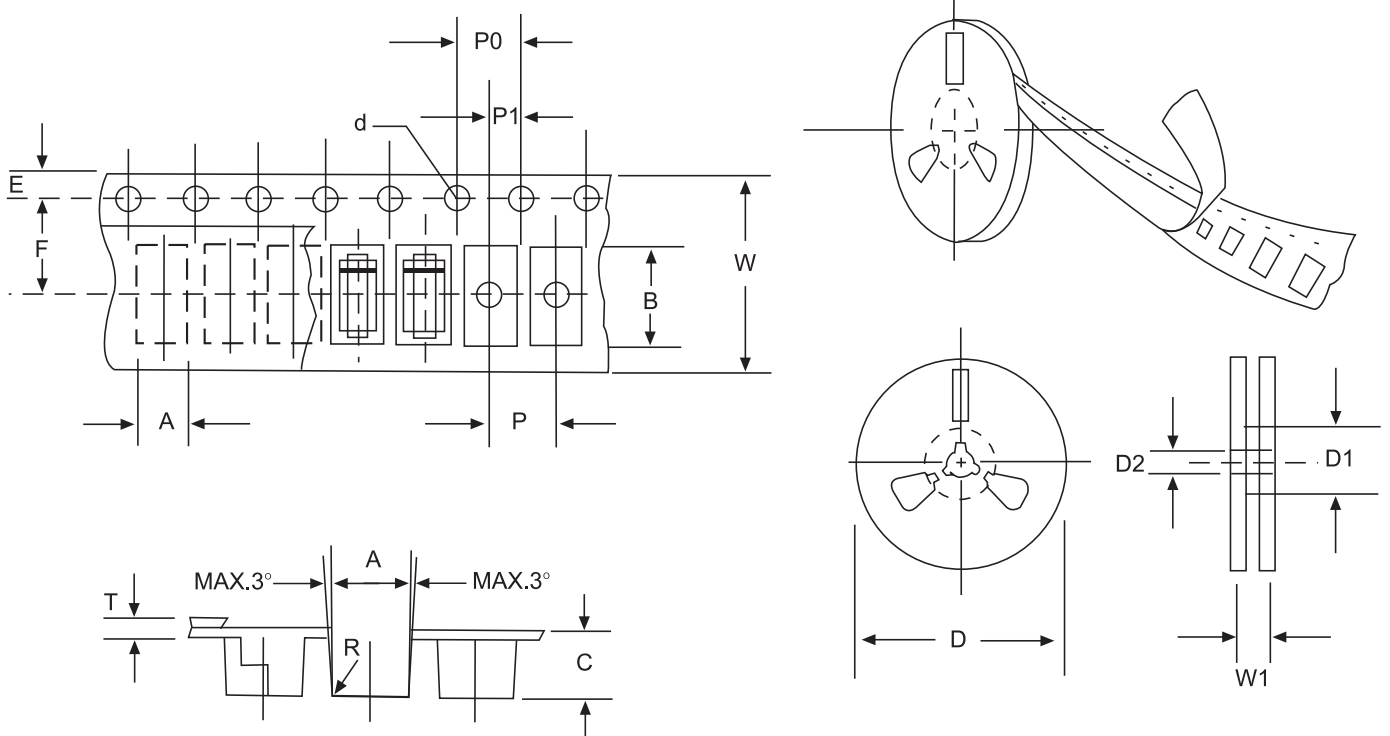


FIG:CONFIGURATION OF AXIAL TAPING

ITEM	SYMBOL	SMBGmm(inch)
Carrier width	A	4.09±0.1(0.161±0.004)
Carrier length	B	5.82±0.1(0.229±0.004)
Carrier depth	C	3.33±0.1(0.131±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.0002)
Reel outside diameter	D	330/178±2.0(13/7.0±0.79)
Reel inner diameter	D1	8.0±0.2(0.315±0.008)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Sprocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	5.65±0.05(0.222±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Total tape thickness	T	0.32±0.1(0.013±0.004)
Tape width	W	12.0±0.2(0.472±0.008)
Reel width	W1	16.8±2.0(0.661±0.079)

NOTE:Devices are packde in accordance with EIA standard RS-481-A and specification given above.